imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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SEMICONDUCTOR

2N5638

N-Channel Switch

- This device is designed for low level analog switchng, sample and hold circuits and chopper stabilized amplifiers.
- Sourced from process 51.



1. Drain 2. Source 3. Gate

Absolute Maximum Ratings * T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{DG}	Drain-Gate Voltage	30	V
V _{GS}	Gate-Source Voltage	-30	V
I _{GF}	Forward Gate Current	50	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

These ratings are based on a maximum junction temperature of 150 degrees C.
These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_C=25°C unless otherwise noted

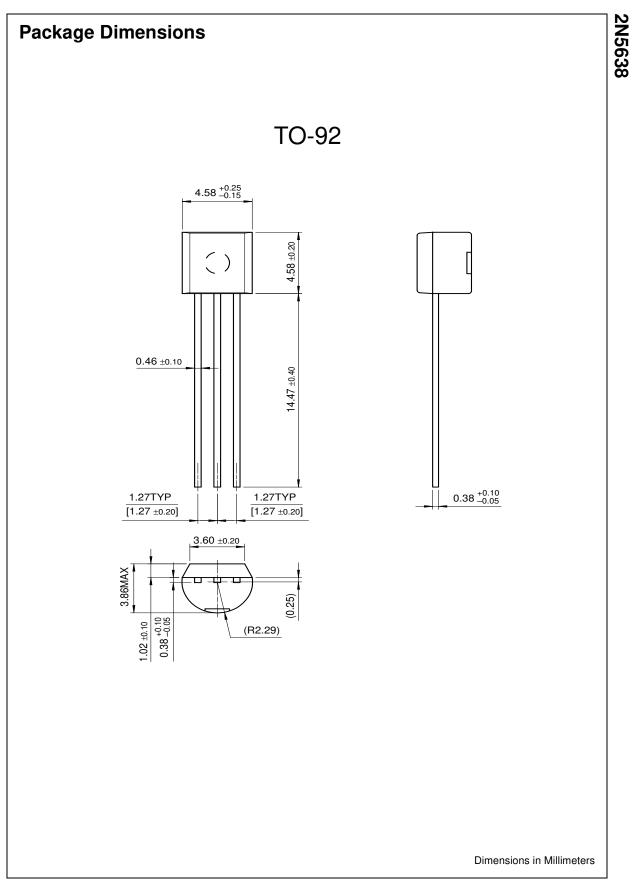
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	cteristics	·			•	
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$V_{DS} = 0, I_{G} = -10\mu A$	-30			V
I _{GSS}	Gate Reverse Current	$V_{GS} = -15V, V_{DS} = 0$			-1.0	nA
I _{D(off)}	Drain Cutoff Leakage Current	V _{DS} = 12V, V _{GS} = 15V			1.0	nA
On Chara	cteristics					
I _{DSS}	Zero-Gate Voltage Drain Current *	$V_{DS} = 20V, I_{GS} = 0$	50			mA
r _{DS(on)}	Drain-Source On Resistance	$V_{GS} = 0V, I_{D} = 1.0mA$			30	Ω
Small Sig	nal Characteristics					
r _{ds(on)}	Drain-Source On Resistance	$V_{DS} = V_{GS} = 0, f = 1.0 kHz$			30	Ω
C _{iss}	Input Capacitance	V _{DS} = 0, V _{GS} = 12V, f = 1.0MHz			10	pF
C _{rss}	Reverse Transfer Capacitance	V _{DS} = 0V, V _{GS} = 12V, f = 1.0MHz			4.0	pF
Switching	Characteristics					
t _{d(on)}	Trun On Delay Time	$V_{DD} = 10V, V_{GS(on)} = 0$			4.0	ns
t _r	Rise Time	$V_{GS(off)} = -12, I_{D(on)} = 12mA$			5.0	ns
t _{d(off)}	Trun Off Delay Time	$R_{G} = 50\Omega$		İ.	5.0	ns
t _f	Fall Time			1	10	ns

* Pulse Test: Pulse Width $\leq 300 \mu s, \, Duty \, Cycle \leq 1.0\%$

Thermal Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Max.	Units	
PD	Total Device Dissipation	350	mW	
-	Derate above 25°C	2.8	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
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